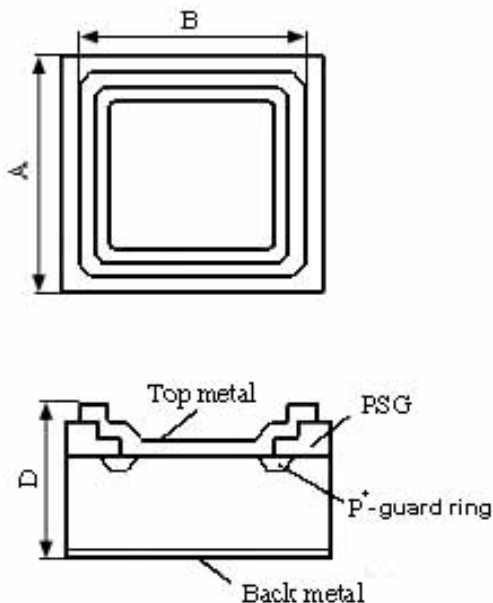




|  |             | 2A/150V. Die Size-45mil. |                   |              |
|--|-------------|--------------------------|-------------------|--------------|
| Electrical Characteristics   | Symbol      | Unit                     | Spec. limit       | Die Sort     |
| Breakdown Voltage @ $I_R=10\text{mA}$  | $V_{BR}$    | V                        | 150               | 160          |
| Average Rectified Forward Current  | $I_{F(AV)}$ | A                        | 2,0               | -            |
| DC Forward Voltage @ $25^\circ\text{C}$ , $I_F=2,0\text{A}$  | $V_F$       | V                        | 0,88              | 0,86         |
| Maximum Reverse Current<br>@ $25^\circ\text{C}$ , $V_R=150\text{V}$<br>@ $125^\circ\text{C}$ , $V_R=150\text{V}$ | $I_R$       | mA                       | 0,005<br>5,0      | 0,003<br>4,0 |
| Peak Forward Surge Current 8,3ms single half sine-wave superimposed on rated load (JEDEC METHOD)                 | $I_{FSM}$   | A                        | 50                | -            |
| Peak Repetitive Reverse Surge Current @ $2,0\mu\text{s}$ , $f=1\text{kHz}$ ., $T_J<175^\circ\text{C}$ .          | $I_{RRM}$   | A                        | 1,0               |              |
| Electrostatic Discharge Voltage. JEDEC Method. ESD HBM. Contact.   | $V_{ESD}$   | kV                       | $\pm 8$ (contact) |              |
| Voltage Rate of Change   | $dV/dt$     | $\text{V}/\mu\text{S}$   | 10.000            |              |
| Operating Junction Temperature   | $T_J$       | $^\circ\text{C}$         | 175               |              |



| DIM               | ITEM                | $\mu\text{m}$ |
|-------------------|---------------------|---------------|
| $A_x$<br>$A_y$    | Wafer Form Die Size | 1150<br>1150  |
| $B_x$<br>$B_y$    | Top Metal Size      | 1030<br>1030  |
| D                 | Thickness           | 300max.       |
| Scribe line Width |                     | 80            |

*Top metal:*  
 a) **Al-Ni-Ag** – for Soldering;  
 b) **Al** – for Wire Bonding.  
 Backside metal: **Ti-Ni-Ag**.